

MDL-III-845nm/1~30mW





SPECIFICATIONS

INFRARED DIODE LASER
AT 845nm

The diode laser module at 845nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.

Wavelength (nm)	845±10		
Output power (mW)	>1, 2, 3, ...,30		
Transverse mode	Near TEM ₀₀		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Warm-up time (minutes)	<5		
Beam divergence, full angle (mrad)	0.5		
Beam diameter at the aperture (mm)	~4.0		
Beam height from base plate (mm)	24.8		
Pointing stability after warm-up (mrad)	<0.05		
Operating temperature (°C)	10~35		
Power supply (90-264VAC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
Expected lifetime (hours)	10000		
Warranty period	1 year		



MxL-III-845	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
 139(L)×73(W)×46.2(H) mm ³ , 0.6kg	 153 (L) ×155(W) ×92 (H) mm ³ , 1.5kg	 133 (L) ×130(W) ×65 (H) mm ³ , 1.2kg	 100 (L) ×62(W) ×56 (H) mm ³ , 0.2kg
